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Growth process control produces high-crystallinity and complete-reaction perovskite solar cells†

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The growth process control (GPC) method, a new method which is better than thermal evaporation, for producing high-crystallinity perovskites by controlling the growth time in a low vacuum, is explored in this work. Inspired by evaporation technology, GPC is an effective method for modifying traditional thermal evaporation and for controlling the crystal growth of perovskite $\text{CH}_3\text{NH}_3\text{I}_3$. Compared to fabrication with the process of co-evaporation, the MAPbI_3 perovskite solar cell fabricated by GPC has high uniformity and film coverage. All of the manufacturing is carried out outside of the glove box. It provides an easy and effective way for perovskite fabrication for industrialization. Here, after using GPC to form perovskite solar cells, the residual methylammonium iodide (MAI) and PbI_2 which is produced by the evaporation process can react completely, observed by time of flight secondary ion mass spectrometry (TOF-SIMS). Finally, formed by GPC, perovskite solar cells exhibit high performance and fewer crystal defects. The electron and hole recombination is greatly reduced. Through the GPC method, the J_{sc} and the filling factor are improved with the increase of time after the fabrication. The power conversion efficiency was increased from 11.12% to 16.4%.

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Introduction

In 2009, the organic–inorganic mixed lead halide perovskite solar cell (MAPbI_3), first proposed by Miyasaka, became a high-potential material due to its low cost and rapid efficiency.^{1–3} The excellent photoelectric properties²⁸ of perovskites are beneficial to apply in various fields such as photovoltaics^{4,5,31} and photoelectric detection.^{6–8} The traditional perovskite as a light-harvesting active layer is mainly based on MAPbI_3 , which is primarily composed of MAI and lead iodide 1 : 1. MAPbI_3 has the typical structure of a perovskite such as ABX_3 .³² There are various phases in MAPbI_3 , depending on the growth temperature. When the temperature is higher than 330 K, MAPbI_3 is in the cubic phase. The cubic phase of the crystal structure of MAPbI_3 with a high temperature has the largest amount of electronic conductivity. Perovskite, as a new absorption layer in solar cells, has a good absorption

coefficient, high electron–hole diffusion length, and carrier mobility under a suitable energy gap. The fabrication of MAPbI_3 as an active layer is mainly divided into a one-step solution process,³³ two-step solution process^{9,10,29,30,34} and thermal evaporation.^{11,12} The one-step solution process is mainly about spin coating MAPbI_3 , which is formed with MAI and PbI_2 powder dissolved in dimethylformamide (DMF) and dimethyl sulfoxide (DMSO), on the indium tin oxide (ITO) substrate, which has been spin-coated with poly(3,4-ethylenedioxythiophene) polystyrene sulfonate (PEDOT:PSS). The two-step solution process involves preparing MAI and PbI_2 dissolved in different solvents and spinning them, respectively, on the hole transport layer to synthesize MAPbI_3 . Although the cost of the solution process²⁷ is low and the operation is not complex, the error tolerance is low in the industrial production of devices. Thermal evaporation is composed of two or more solid materials (such as MAI and PbI_2 powder) that react with each other on the substrate evaporated by constant temperature or by electron beam heating in a high vacuum.^{24,25} In recent years, doping engineering and solvent engineering have also been developed to improve the crystallization of perovskite.²⁶ Because the procedure of solid evaporation is stable, the fabrication of perovskite as an active layer *via* thermal evaporation has a high yield, but the price of this is relatively high. In addition, the perovskite solar cell made *via* thermal evaporation is easy to decompose at a high temperature, and it may cause the problem of the incomplete reaction of MAI and PbI_2 , seriously

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affecting the transmission of electrons and holes. Although using thermal evaporation can stably produce a large number of perovskite solar cells, problems such as excess PbI_2 and the easy decomposition of MAI restrict the development of mass production. Therefore, the vapor-assisted solution process (VSVP)¹³ developed in recent years combines the advantages of the solution process and the thermal evaporation, which can not only reduce the cost of evaporation but also improve the error tolerance in production.

In our study, the original VSVP was modified *via* a method that our lab invented, the so-called sandwich evaporation technique (SET).^{14,15} In addition, the growth process control (GPC) method further improved the SET. MAPbI_3 is formed *via* the reaction of $\text{MAI-PbI}_2\text{-MAI}$. The formation rate of MAPbI_3 can be controlled by using MAI as a bottom layer, as well as double diffusion (MAI forms the upper and lower layers diffused to PbI_2 ; this results in better planeness). In addition, through using MAI as the bottom layer, the grains with a uniform orientation can be obtained, which is beneficial for carrier separation and photocurrent generation. On the basis of double diffusion, we found that MAPbI_3 formed *via* the evaporation of $\text{MAI-PbI}_2\text{-MAI}$ would crystallize gradually with time, and the performance of the solar cell would improve after several days of storage and controlling in a low vacuum. We call it GPC technology. The concepts of double diffusion and a seed layer promoted the crystallization of perovskite films. The perovskite solar cells fabricated by GPC finally reached a power conversion efficiency (PCE) of 16.4%.

Fabrication

The fabrication of perovskite solar cells is schematically shown in Fig. 1. ITO substrates were cleaned using acetone, isopropyl alcohol, and methanol for 15 min, then treated with UV-ozone for 10 min. Next, the treated ITO-coated substrates were spin-coated with PEDOT:PSS (PEDOT-4083, purchased from CLEVIOTM) at 3000 rpm for 30 s and annealed at 120 °C for 15 min in the air. The solution of $\text{CH}_3\text{NH}_3\text{I}$ (MAI) dissolved in dimethylformamide (DMF) with 20 mg ml^{-1} , and was spin-coated onto the transport layer as the bottom layer at 3000 rpm for 30 s and annealed at 100 °C for 10 min in the air. After drying, the PbI_2 was evaporated on the precursor layers with a thickness of 185 nm *via* evaporator with the rate of 0.03 nm s^{-1} . Then, the MAI powder was evaporated by the homemade SET chamber to form perovskite for 30 min. The size of the homemade SET chamber is 2800 cm^3 and the distance between sample and MAI powder is 7.5 cm. The remaining MAI was cleaned by spin-coating isopropanol (IPA) at 3000 rpm for 30 s and annealed at 100 °C for 5 minutes to get a smooth surface and a deep-brown-color perovskite layer. Then it was annealed at 120 °C with spin-coating PC_{60}BM (phenyl-C60-butyric acid methyl ester) onto the perovskite/PEDOT:PSS/ITO substrate at 1300 rpm for 60 s. Finally, the BCP and the silver were evaporated by thermal deposition with thicknesses of 5 nm and 120 nm, respectively. All of our devices were preserved in a low-vacuum chamber at 0.13 Pa on the first day to the seventh day for controlling the growth process (MAI and PbI_2), and they were measured in the ambient atmosphere at room temperature.

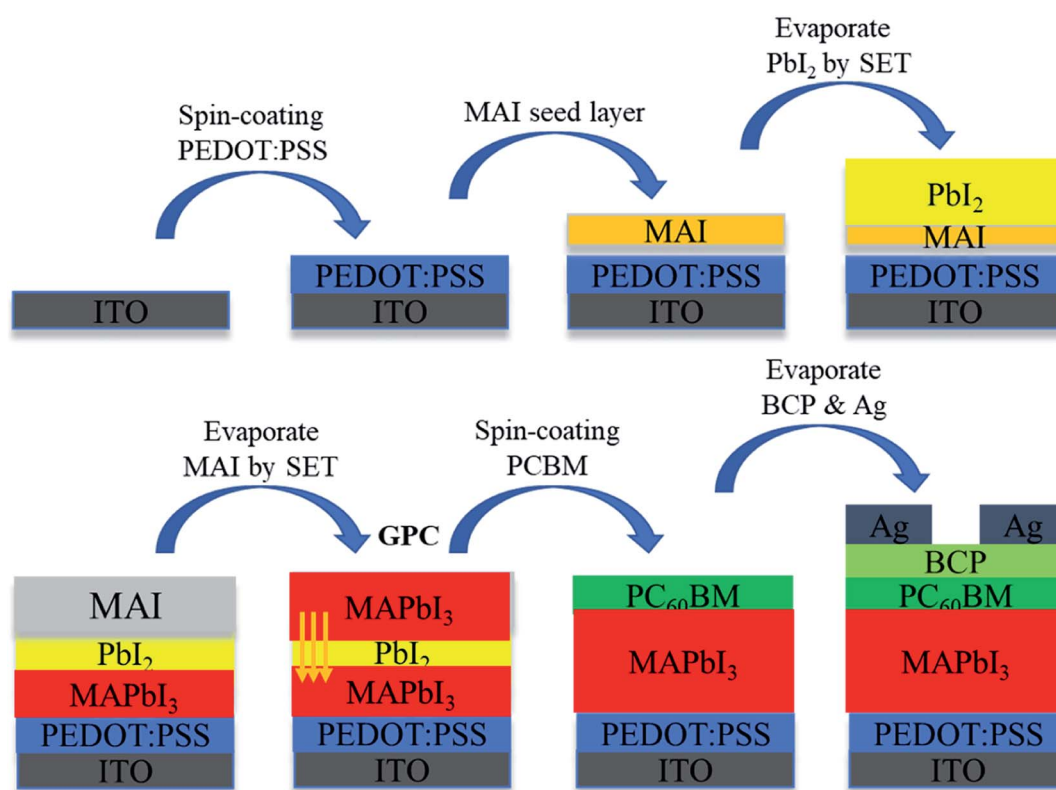


Fig. 1 Fabrication of perovskite solar cells.

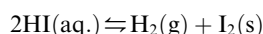
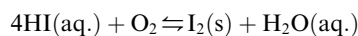
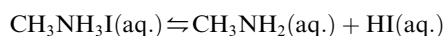


Result and discussion

In the solution process,^{16–23} MAPbI₃ needed to be manufactured in a nitrogen environment. However, in this research, all of the coating and annealing processes were carried out outside of the glove box. This would contribute to mass production and to the reduction of cost. For device fabrication, the solution process depends on the friction generated from the solution coated on the substrate. This could cause poor film coverage and uniformity, in addition to problems of bad crystallization or too small particle size due to the formation of a perovskite active layer in a short period of time. However, the SET can be used to improve the quality of the film.

After all of the components were completed, we measured the perovskite solar cells for the first time. Our device was kept in a low-vacuum state for several days, and then, the efficiency of the device was measured and observed repeatedly. We found that the performance of our perovskite solar cells gradually improved with the increase of time. In addition, the open circuit voltage, short circuit current, and filling factor were significantly improved. Therefore, we call this GPC post-treatment technology, which combines the SET and low-vacuum controlling. Besides, after making perovskite solar cells by sandwich evaporation method, we keep our devices at room temperature. The low temperature helps the GPC process proceed at a slow rate. Using GPC post-treatment technology, we found that the crystallization of MAPbI₃ perovskite became better. Solar cells with MAPbI₃ as the active layer had relatively higher photoelectric conversion efficiency. This is not only of great significance to the large-scale production of perovskite solar cells but also it has the opportunity to improve the efficiency of various components of perovskite materials. Our perovskite solar cells adopted the pin structure of ITO/PEDOT:PSS/MAPbI₃/PC₆₀BM/BCP/Ag.

In the traditional evaporation process, MAI and PbI₂ are respectively or simultaneously heated and evaporated in a high-vacuum evaporation machine to form MAPbI₃. This is called thermal evaporation or the co-evaporation method, respectively. Being heated by the evaporator to evaporate MAI and PbI₂ can make the reaction rate more uniform, and MAPbI₃ with a better surface quality can be made. However, the evaporation time and required temperature of PbI₂ and MAI are different. MAI as an organic material is easy to decompose at a high temperature.



Therefore, it is hard to control the evaporative rate of MAI, and this will cause an excess of PbI₂. The residual PbI₂ will block the separation of electron holes and affect the transmission of a photocurrent. Therefore, in this study, MAI as a bottom layer dissolved in DMF was spin-coated on the substrate that grew PEDOT:PSS. PbI₂ and MAI were evaporated by SET, respectively,

through the thermal evaporator and SET, just like a sandwich: PbI₂ was in the middle and was used to have double diffusion for the reaction of MAI and PbI₂.

In order to demonstrate that GPC could effectively overcome the difficulties of incomplete reaction between MAI and PbI₂ in traditional evaporation method, time of flight secondary ion mass spectrometry (TOF-SIMS) was used to measure the depth distribution of elements in MAPbI₃, which was formed by SET and GPC post-processing technology. The C₆₀ acted as excitation source in TOF-SIMS, which was able to not only avoid the damage of organic cation as CH₃NH₃I⁺(MA⁺) caused by high energy source generated by Ar⁺ as excitation source in SIMS, but also acquire the information of the depth distribution of MA⁺ metal ion of lead (Pb²⁺) and the ion of iodine (I⁻) in perovskite, simultaneously. As shown in Fig. 2, we utilized the SIMS to check the element distribution in different stages of SET with and without GPC post treatment.

Fig. 2(d) shows the distribution of elements. Part of the organic macromolecular group MA⁺ penetrated into PbI₂, and the rest of MA⁺ was retained at the border of PbI₂ and ITO. Fig. 2(c) shows the double diffusion by adopting SET to complete the upper-layer of MAI. The double diffusion enables the MAI to gradually combine with PbI₂ to form MAPbI₃. From the depth element distribution measured in Fig. 2(e), we found that there was a great quantity of PbI₂ in the newly completed components. It would be an energy barrier between the active layer and the hole transform layer, which hinders the transfer of carriers. This was also the reason why traditional evaporation method cannot be carried out in the large-scale production. Although the perovskite solar cells produced in the evaporation process have better flatness and fewer defects than the production in the solution process, residue of PbI₂ seriously hinders the separation and transmission of carriers, which was fatal for solar energy. Therefore, we introduce GPC post-processing treatment to preserve our devices after a few days under low vacuum condition. We found that the excessive PbI₂ gradually decreased. Fig. 2(f) shows that the content of PbI₂ significantly reduces after four days of GPC treatment. Fig. 2(g) shows that the PbI₂ entirely disappears after one week of GPC treatment, and the MAI and PbI₂ react completely, which is very exciting for the large-scale production of perovskite solar cells by vaporization. The whole reaction of GPC post treatment is shown in Fig. 2(h). The distribution of elements in CH₃NH₃PbI₃ is discussed in ESI.†

Compared with the traditional evaporation method, GPC can effectively deal with residual PbI₂. In general, if the PbI₂ film is too thin, the MAI cannot penetrate it effectively and form perovskite crystals completely. In addition, the influence of insufficient permeability can be reduced by using double diffusion. However, the discontinuous infiltration of MAI may cause a decrease in the number of crystalline particles. Due to the double diffusion of MAI–PbI₂–MAI, the perovskite solar cells can be stored in a low vacuum after fabrication, which is beneficial for the diffusion of MAI from the upper and lower layers to the sandwich's intermediate layer, and then, the growth of the perovskite in the active layer can be controlled until it completely reacts.



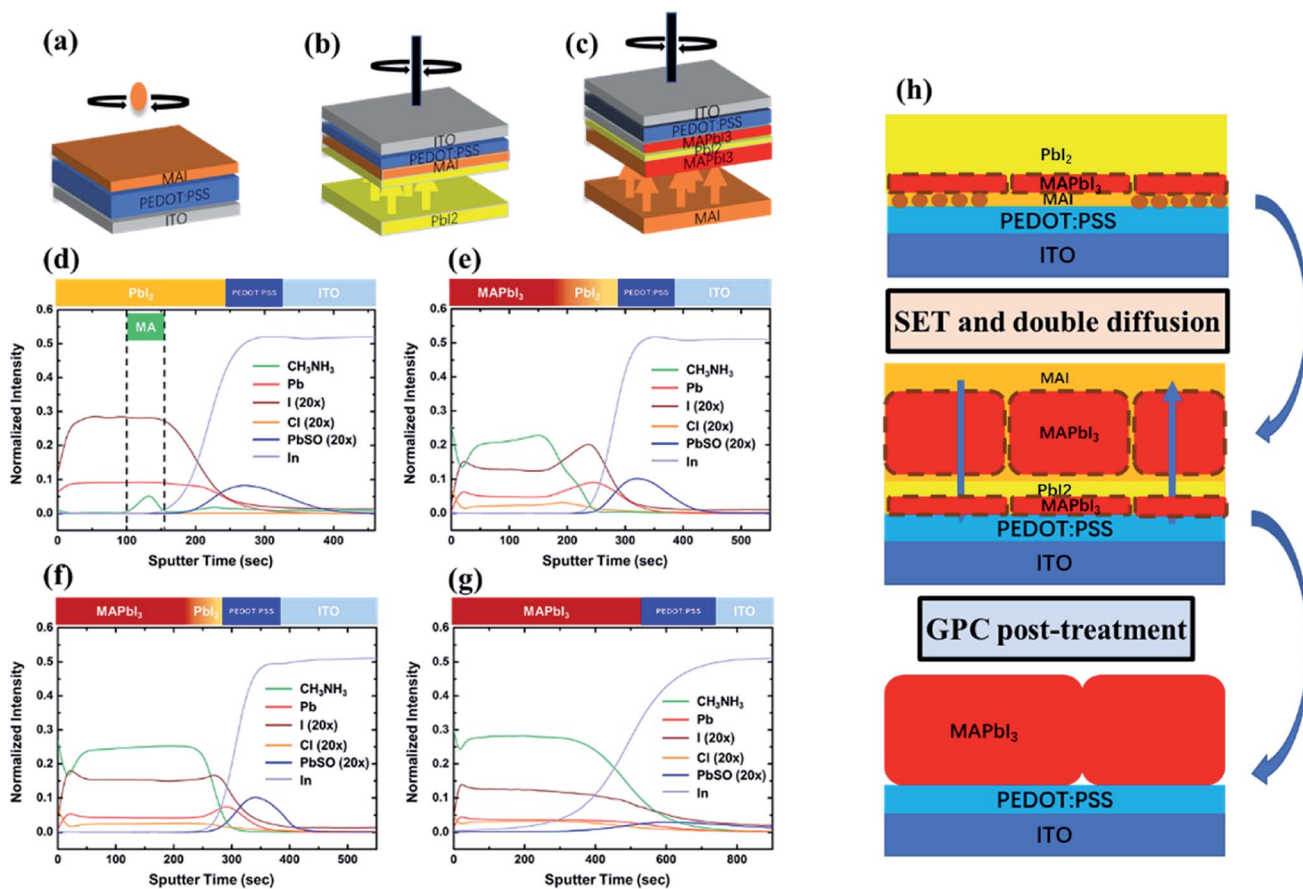


Fig. 2 (a) MAI as seed layer was spin-coated on ITO which was coated with PEDOT:PSS. (b and c) PbI₂ and MAI power was evaporated on the MAI seed layer by homemade SET chamber, respectively. (d) The depth distribution with PbI₂ being evaporated on the MAI seed layer. (e) MAI powder was evaporated as the top layer without GPC. (f) MAI powder was evaporated as the top layer with GPC for 4 days and (g) for a week later. (h) The principle for the GPC.

The high-crystallinity MAPbI₃ perovskite active layer can be made, and then, the perovskite solar cells with excellent performance can be produced. By using GPC, we analyzed the film change of the perovskite as an active layer, as shown in Fig. 3.

Fig. 3 (a) and (b) show the X-ray Diffraction (XRD) patterns of X-ray with angles of 0 to 50 degrees and 15 to 50 degrees treated with GPC for 1 day, 3 days, 5 days, and 7 days. According to the 2theta angles measured by XRD, it can be found that at 2theta = 12.6°, it is mainly the crystallization of PbI₂ in the direction of (0,0,1), whereas the main crystallization peaks of perovskite appear at 2theta = 14.05° (1,1,0), 28.41° (2,2,0), 31.7° (3,1,0). The crystallization of MAPbI₃ as an active layer and the bond of Pb–I in PbI₂ can be shown by X-ray diffraction. We can see that the strength of the main peak of the perovskite made on the first day is about 2500, and the strength of the main peak gradually rises with the GPC for several days. This proves that the crystal state of the perovskite, which is controlled for several days in a low vacuum, became better. We can see that the intensity increased with time, and the maximum diffraction intensity is more than 5000. Fig. 3(c) shows the absorption of perovskite for the first to seventh day, which was made *via* GPC. The absorption spectrum can be used to characterize the storage capacity of photons in different wavelengths. If the absorption of the

photons of the perovskite active layer is stronger, the probability of conversion to electrons will be higher. Therefore, the absorption of perovskite improved with time, and the probability of photons converting into a photocurrent increased. This was beneficial for the improvement of the short-circuit current. Fig. 3(d) shows the photoluminescence (PL) spectrum of the perovskite fabricated *via* GPC for 1 to 6 days. The band gap of the photoluminescence spectrum of perovskite is similar to that of the absorption spectrum. Therefore, the stronger the photoluminescence, the fewer the impurities between energy bands due to defects, and the less leakage current one has, which is beneficial for the improvement of the short-circuit current. The luminous wavelength of MAPbI₃ is about 750 nm, and we can see that the spectral intensity increased for the same phenomenon. After GPC, the reaction of MAPbI₃ is gradually completed, so the absorption of perovskite is improved. Hence more photons are converted into electrons. After the GPC process, the TOF-SIMS shows that PbI₂ is completely eliminated, and then the energy level barrier caused by PbI₂ disappears. It is conducive to the improvement of short-circuit current after solving the problem of residual PbI₂ which often occurs in the traditional evaporation technology.



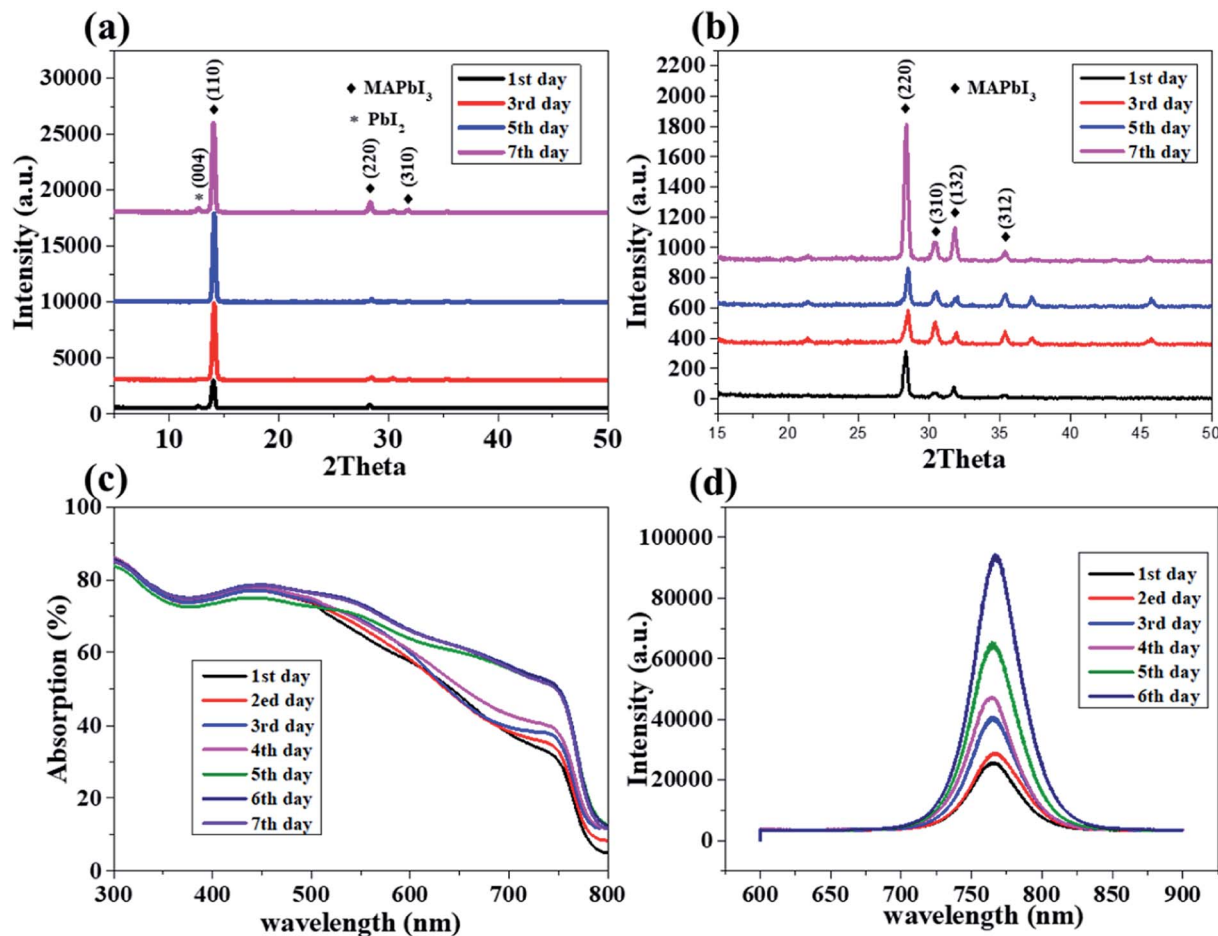


Fig. 3 The perovskite solar cells made *via* GPC with (a) XRD of 2theta for 5–50 degrees, (b) 2theta for 15–50 degrees, (c) absorption, and (d) PL on different days.

In this research, we measured the J - V curves of day 1, and a week later, respectively, as shown in Fig. 4(a). The voltage and current density of Fig. 4(a) at different times show that the

perovskite made *via* the SET will be preserved in a low vacuum for several days, the performance will be significantly improved, and each index will be further optimized. The comparison of

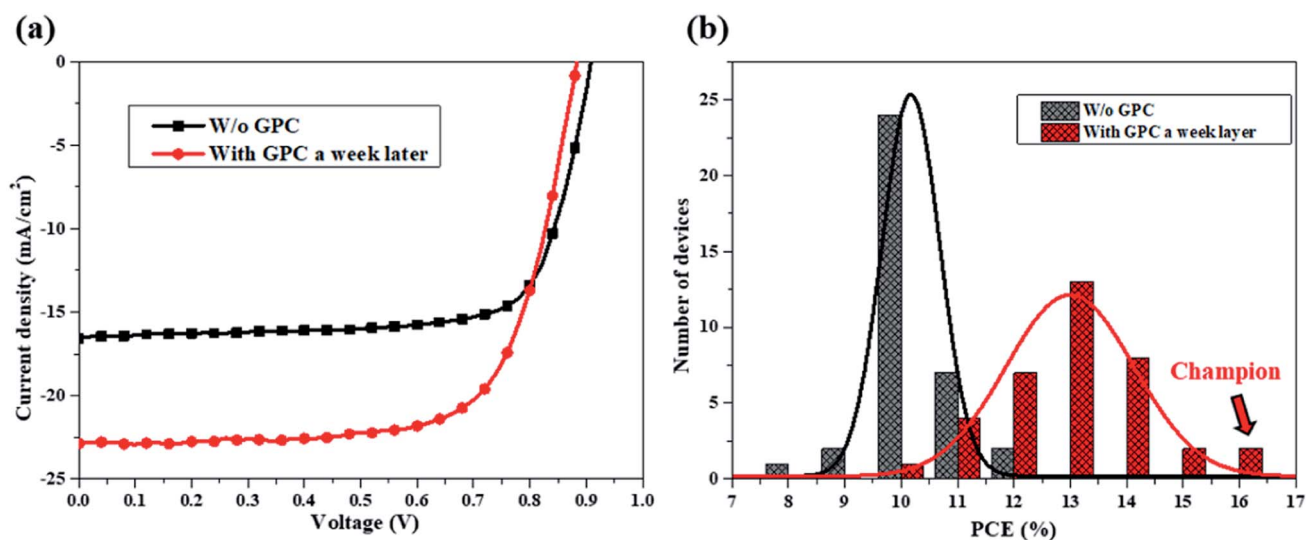


Fig. 4 (a) Number of device (b) J - V curve, of perovskite solar cells prepared w/o GPC and with GPC a week later.



Table 1 Device performance parameters of perovskite solar cells prepared *via* with and w/o GPC

GPC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
W/o GPC	0.91	16.60	73.80	11.12
With GPC for a week later	0.91	23.79	76.20	16.43

perovskite solar cells is given in ESI.† Fig. 4(b) shows the number of devices which are treated with and without GPC. Our devices show good reproducibility, the efficiency is located from 11.2% to 16.4% for nearly 40 devices, and most of the PCEs are about 13%. Therefore, the champion device reached the maximum efficiency as 16.4% on a week later. The curve represents the Gaussian function of the histogram. The specific numerical parameters are shown in Table 1 below. Therefore, the perovskite solar cells fabricated *via* GPC can reach a comparably high efficiency as long as the growing time is effectively controlled. This is beneficial for industrial production.

Furthermore, solar cells often need process of aging, and the completion time of components is determined by the time when the cells are made. Therefore, compared with the traditional evaporation method, our SET to form perovskite solar cell can reduce the time of fabrication, the GPC process can slow down the crystallization rate of the film and enable the large crystals to gradually form. Thus, it is conducive to industrial production. The component statistics of perovskite solar cells with and without GPC are given in ESI.†

As shown in Fig. 5(c), the SEM showed the cross-section of the new perovskite formed by GPC. It could be seen from the figure that the perovskite solar cell was completed without GPC. There existing a layer of an incomplete reaction PbI_2 hinders the carrier transport. In comparison, the PbI_2 residual layer disappeared, and the cross-section of perovskite became more uniform, as shown in Fig. 5(d) for the SEM image of the perovskite preserved in a low vacuum for a week. We speculate that the reaction speed of PbI_2 and MAI will slow down in the condition of a low vacuum. Keeping the perovskite solar cell in the vacuum state is beneficial for controlling the formation rate of $MAPbI_3$, and a perovskite material with better crystallinity can be obtained. From the cross-sections taken with SEM without GPC and with GPC for a week later, we found that the particles in the newly completed perovskite active layer were smaller. There were many gaps between crystals of perovskite, and they are not uniform in the beginning. However, after a week of low-vacuum control, the speed of crystallization in the low-vacuum state becomes slower, the crystallinity gradually becomes better, and the defects are decreased. This is very helpful for reducing the leakage current and for the improvement of the short-circuit current.

Fig. 6 below shows a summary of the statistical results of parameters with and w/o GPC post-processing of perovskite solar cell devices made with SET. After the GPC, the figure shows that (a) V_{oc} , (b) J_{sc} and (c) fill factor are improved, and the quality of the perovskite film is tuned into better condition. (d) R_s decreases due to the reduction of excess reactant hindrance like PbI_2 .

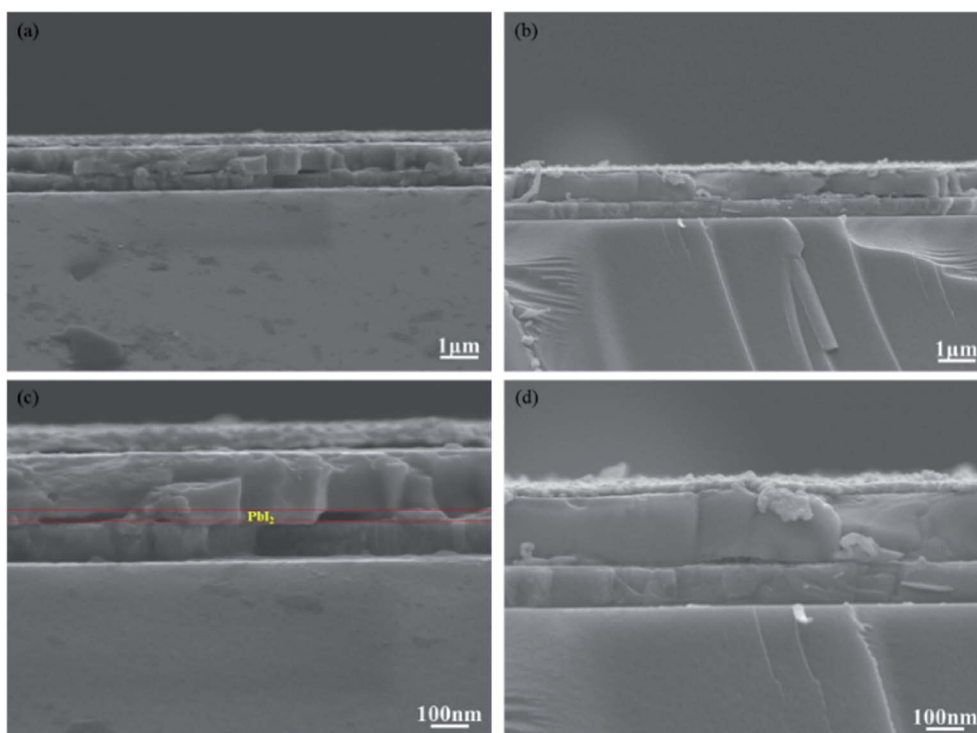


Fig. 5 SEM cross-section (a) without GPC and (b) with GPC for a week later at 20 000 times magnification. (c) Without GPC and (d) with GPC for a week later at 50 000 times magnification.



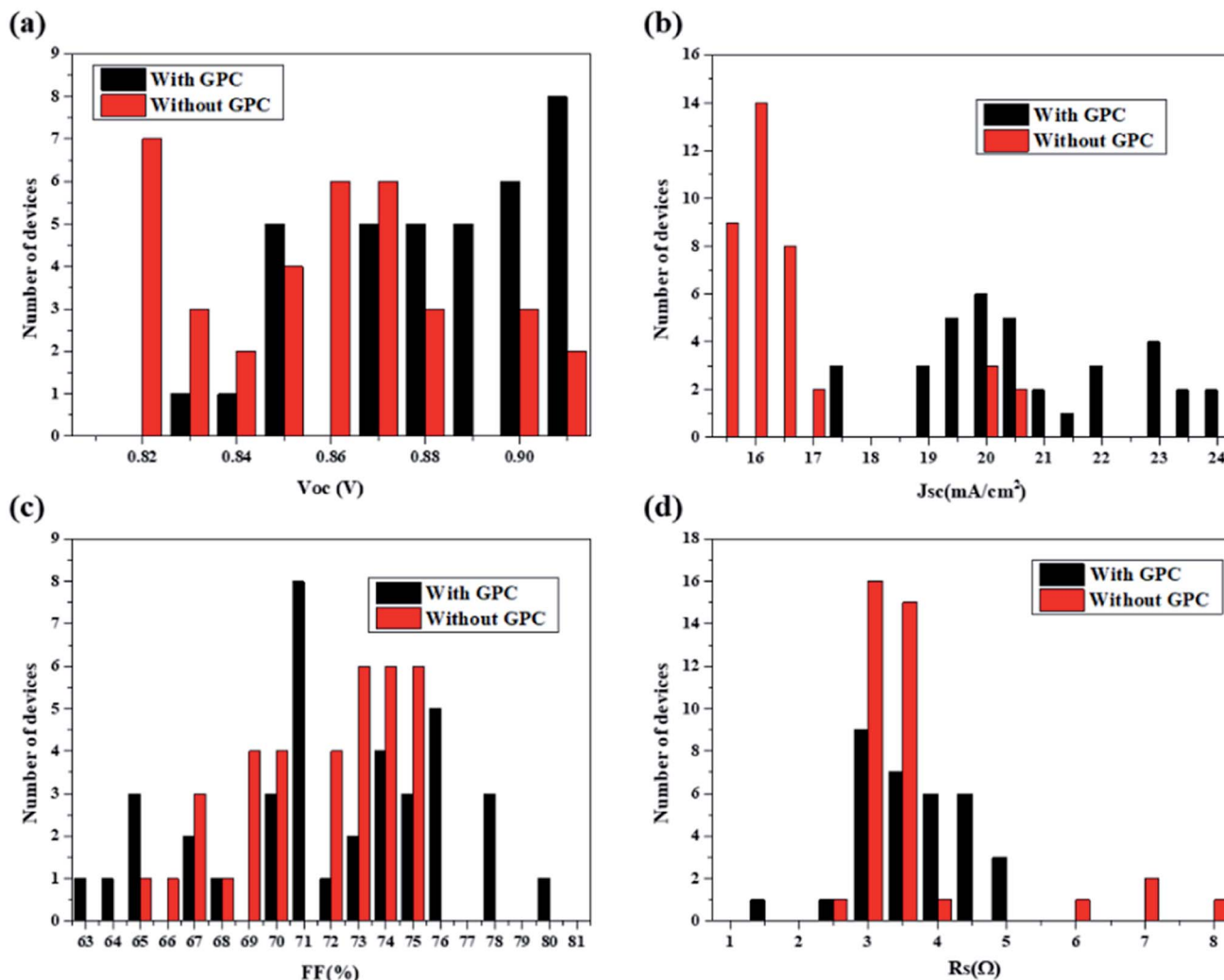


Fig. 6 The number of devices for (a) V_{oc} , (b) J_{sc} , (c) FF, (d) R_s of MAPbI₃ perovskite solar cell which was made without GPC and with GPC for a week later.

Conclusion

It is difficult to produce perovskite solar cells on a large scale through the solution process only, whereas the perovskite fabricated *via* the thermal evaporation process has a good yield and high error tolerance. However, there are some problems. For example, it is hard for the synthetic materials of perovskite (such as MAI and PbI₂) to react completely, which will cause an unnecessary energy band to affect the transmission of electronic and hole. In addition, it will make the cost of fabrication relatively high. In this study, the MAI dissolved in DMF was used as the bottom layer to evaporate PbI₂ and MAI with SET, and the final device was kept in a low vacuum for a period of time. Preservation in a low vacuum slows down the formation of MAPbI₃. This made the crystallinity of CH₃NH₃I₃ as an active layer better, and the device performance was further improved. The optimized perovskite solar cell experienced excellent improvement with $J_{sc} = 23.79 \text{ mA cm}^{-2}$, $V_{oc} = 0.91 \text{ V}$, FF = 76.2%, and PCE = 16.43%, respectively. In addition, the entire

process was carried out outside of the glove box, which was beneficial for the experimental operation and cost savings. Furthermore, this method is beneficial for industrial production.

Methods

Current density–voltage (J – V) characteristics were measured with a Keithley 2400 source under AM 1.5G at an intensity of 1000 W m^{-2} . X-ray diffraction (XRD) data were collected using an X-ray powder diffractometer PW3040 with Cu-K α radiation. Scanning electron microscopy (SEM) images were analyzed on a JEOL JSM-7600F microscope using a 10 kV field emission.

All time-of-flight secondary-ion mass spectrometry (ToF-SIMS) depth profiles were acquired using a PHI TRIFT V nanoTOF (ULVAC-PHI, Japan) system with a dual beam sputter-and-view scheme. In the analysis phase, a pulsed C60+ (approximately 8200 Hz, pulse length of 15 ns) rastering over a $100 \mu\text{m} \times 100 \mu\text{m}$ area was applied as the primary ion. The



acceleration voltage of the incident C60+ ion was 20 kV and the beam current was 0.08 nA-DC. As for the sputter phase, a 3 kV Ar⁺ beam with beam current of 100 nA rastering over a 1500 μm × 1500 μm area was utilized to remove the top surface material. These parameters were determined based on our previous study to eliminate the depth profile artifacts of perovskite materials.³⁵

All the XPS spectra were acquired by a PHI 5000 VersaProbe (ULVAC-PHI, Japan) system. During data acquisition, a monochromatic Al Kα X-ray beam with diameter of 100 μm was illuminated on the sample surface while it was neutralized by an e⁻ and an Ar⁺ beam, both with an acceleration voltage of 10 V, to avoid surface potential build-up.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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